General purpose transistor (isolated transistor and diode)

QSL12

A 2SD2675 and a RB461F are housed independently in a TSMT5 package.

Applications

DC / DC converter Motor driver

Features

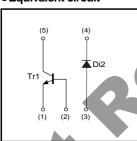
1) Tr : Low VcE(sat) Di : Low VF

2) Small package

Structure

Silicon epitaxial planar transistor Schottky barrier diode

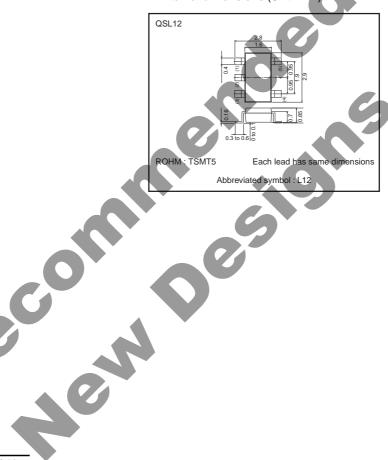
●Equivalent circuit



Packaging specifications

Туре	QSL12
Package	TSMT5
Marking	L12
Code	TR
Basic ordering unit(pieces)	3000

●External dimensions (Unit : mm)



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	30	V
Collector-emitter voltage	Vceo	30	V
Emitter-base voltage	VEBO	6	V
Collector current	Ic	1	Α
Collector current	ICP	2	A *1
Power dissipation	Pc	0.9	W/ELEMENT *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-40 to +125	°C

Di2

Parameter	Symbol	Limits	Unit
Peak reverse voltage	VRM	25	V
Reverse voltage (DC)	VR	20	V
Average rectified forward current	lF	700	mA
Forward current surge peak (60Hz, 1∞)	Iгsм	3	Α
Power dissipation	Po	0.7	W/ELEMENT *
Junction temperature	Tj	125	°C
Range of storage temperature	Tstg	-40 to +125	°C

^{*} Mounted on a 25mm×25mm×10.8mm ceramic substrate

Tr1&Di2

Parameter	Symbol	Limits	Unit
Total power disipation	D-	0.5	W/TOTAL *1
	Pb	1.25	W/TOTAL *2

^{*1} Each terminal mounted on a recommended land. *2 Mounted on a 25mm×25mm×¹0.8mm ceramic substrate.

●Electrical characteristics (Ta=25°C)

Tr1

111								
Parameter		Symb	bol	Limits		Uı	nit	
Collector-base voltage		Vсв	10	30		١	/	
Collector-emitter voltag	je	Vce	0	30		١	/	
Emitter-base voltage		VEB	0	6		١	/	
Collector current		lc	_	1			4	
		ICP		2			4	*1
Power dissipation		Pc		0.9	\		MENT	- *2
Junction temperature		Tj		150			<u>C</u>	<u></u>
Range of storage temp *1 Single pulse, Pw=1ms	erature	Tst	g –4	0 to +12	25	٥(<u>. </u>	<u> </u>
*2 Mounted on a 25mm×25mm	n×t0.8mm ce	ramic s	substrate					
Di2								
Parameter		5	Symbol	Lin	nits		Unit	
Peak reverse voltage			Vrм	2			V	
Reverse voltage (DC)			VR		0		V	
Average rectified forwa		_	lF		00		mΑ	
Forward current surge per	ak (60Hz, 1	1∞)	IFSM		3		Α	
Power dissipation			PD	0.		W/	ELEMI	ENT *
Junction temperature			Tj		25		°C	
Range of storage temp * Mounted on a 25mm×25mm×			Tstg	_40 to	+125		°C	
Tr1&Di2								
Parameter	Symbol		imits.		Unit			
Total power disipation	Pp		0.5		/TOT/			
*1 Each terminal mounted on a	- rooommon		1.25	W	/TOT/	1L *2		
*2 Mounted on a 25mm×25mm	n×t0.8mm cer	ramic s	substrate.					
●Electrical character	istics (Ta	=25°	°C) 🚄					_ (//)
Tr1			′					
Parameter		И	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdo		-	ВУсво	30	тур.	iviax.	V	Ic=10μA
					_	_	V	•
Collector-emitter break		ige	BVCEO	30	-	7	_	Ic=1mA
Emitter-base breakdow	n voltage		ВУЕВО	6	-		V	IE=10μA
Collector cutoff current			Ісво	-		100	nA	Vcb=30V
Emitter cutoff current		\perp	ІЕВО	16	7	100	nA	Veb=6V
Collector-emitter satura	tion voltag	ge	VCE(sat)	1	120	350	mV	Ic/I _B =500mA/25mA
DC current gain			hfe	270	-	680	_	Vce/lc=2V/100mA
Transition frequency			fr	7	320	_	MHz	Vce=2V, Ie=-100mA, f=100MHz
Collector output capacit	tance		Cob	-	7	_	pF	Vcb=10V, Ie=0A, f=1MHz
* Pulsed								

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	450	490	mV	I _F =700mA
Reverse current	IR	-	_	200	μΑ	V _R =20V
Reverse recovery fime	trr	_	9	-	ns	IF=IR=100mA, Irr=0.1IR



^{*1} Single pulse, Pw=1ms *2 Mounted on a 25mm×25mm×¹0.8mm ceramic substrate

•Electrical characteristic curves

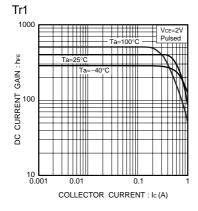


Fig.1 DC current gain vs. collector current

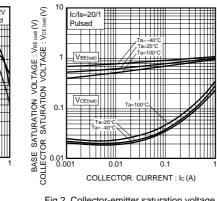


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

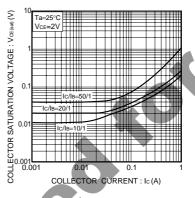


Fig.3 Collector-emitter saturation voltage vs. collector current

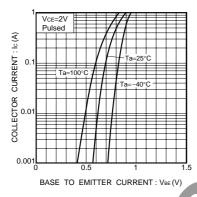


Fig.4 Grounded emitter propagation characteristics

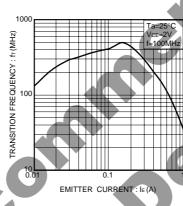


Fig.5 Gain bandwidth product vs. emitter current

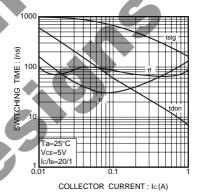


Fig.6 Switching time

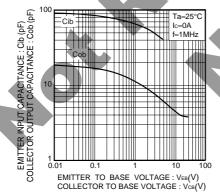


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage



Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
 means without prior permission of ROHM CO..LTD.
- The contents described herein are subject to change without notice. The specifications for the
 product described in this document are for reference only. Upon actual use, therefore, please request
 that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
 use and operation. Please pay careful attention to the peripheral conditions when designing circuits
 and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
 otherwise dispose of the same, no express or implied right or license to practice or commercially
 exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

